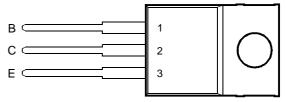
- Designed for Complementary Use with the BD544 Series
- 70 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- 10 A Peak Collector Current
- Customer-Specified Selections Available

### TO-220 PACKAGE (TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDTRACA

### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT
	BD543		40	
Collector-base voltage (I <sub>E</sub> = 0)	BD543A	\/	60	V
	BD543B	V <sub>CBO</sub>	80	
	BD543C		100	
Collector-emitter voltage (I <sub>B</sub> = 0)	BD543		40	
	BD543A	\/	60	V
	BD543B	V <sub>CEO</sub>	80	
	BD543C		100	
Emitter-base voltage			5	V
Continuous collector current			8	Α
Peak collector current (see Note 1)			10	Α
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W
Operating free air temperature range			-65 to +150	°C
Operating junction temperature range			-65 to +150	°C
Storage temperature range			-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			260	°C

NOTES: 1. This value applies for  $t_p \le 0.3$  ms, duty cycle  $\le 10\%$ .

- 2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.



# BD543, BD543A, BD543B, BD543C NPN SILICON POWER TRANSISTORS

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# electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA (see Note 4)	I <sub>B</sub> = 0	BD543 BD543A BD543B BD543C	40 60 80 100			V
I <sub>CES</sub>	Collector-emitter cut-off current	$V_{CE} = 40 \text{ V}$ $V_{CE} = 60 \text{ V}$ $V_{CE} = 80 \text{ V}$ $V_{CE} = 100 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	BD543 BD543A BD543B BD543C			0.4 0.4 0.4 0.4	mA
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> = 30 V V <sub>CE</sub> = 60 V	$I_{B} = 0$ $I_{B} = 0$	BD543/543A BD543B/543C			0.7 0.7	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0				1	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_{C} = 1 A$ $I_{C} = 3 A$ $I_{C} = 5 A$	(see Notes 4 and 5)	60 40 15			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	$I_B = 0.3 \text{ A}$ $I_B = 1 \text{ A}$ $I_B = 1.6 \text{ A}$	$I_{C} = 3 A$ $I_{C} = 5 A$ $I_{C} = 8 A$	(see Notes 4 and 5)			0.5 0.5 1	V
V <sub>BE</sub>	Base-emitter voltage	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 5 A	(see Notes 4 and 5)			1.4	V
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 kHz	20			
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 MHz	3			

NOTES: 4. These parameters must be measured using pulse techniques,  $t_p$  = 300  $\mu$ s, duty cycle  $\leq$  2%.

### thermal characteristics

PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.79	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

# resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 6 A	$I_{B(on)} = 0.6 A$	$I_{B(off)} = -0.6 \text{ A}$		0.6		μs
t <sub>off</sub>	Turn-off time	$V_{BE(off)} = -4 V$	$R_L = 5 \Omega$	$t_{\rm p} = 20 \ \mu \rm s, \ dc \le 2\%$		1		μs

 $<sup>\ ^{\</sup>dagger}\ \ \text{Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.}$ 

### PRODUCT INFORMATION

<sup>5.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

### TYPICAL CHARACTERISTICS

# 

Figure 1.

### **COLLECTOR-EMITTER SATURATION VOLTAGE**

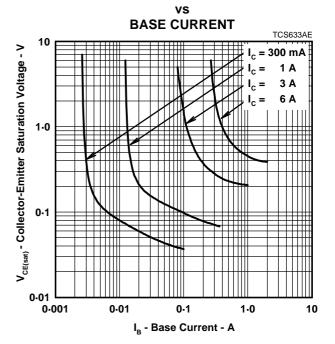
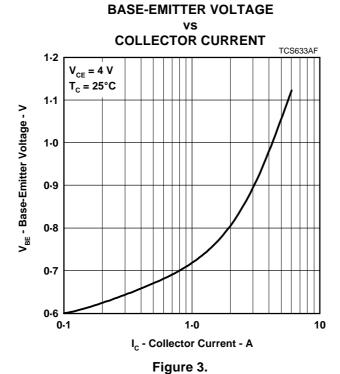
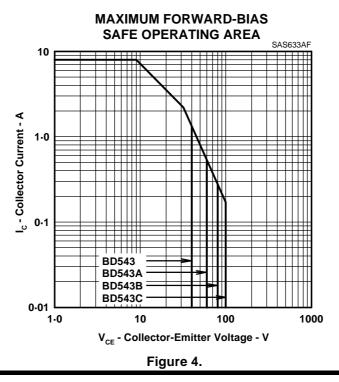


Figure 2.



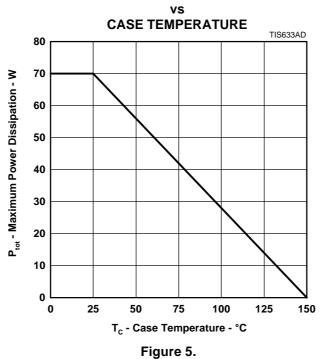
Power

### **MAXIMUM SAFE OPERATING REGIONS**



### THERMAL INFORMATION

### **MAXIMUM POWER DISSIPATION**



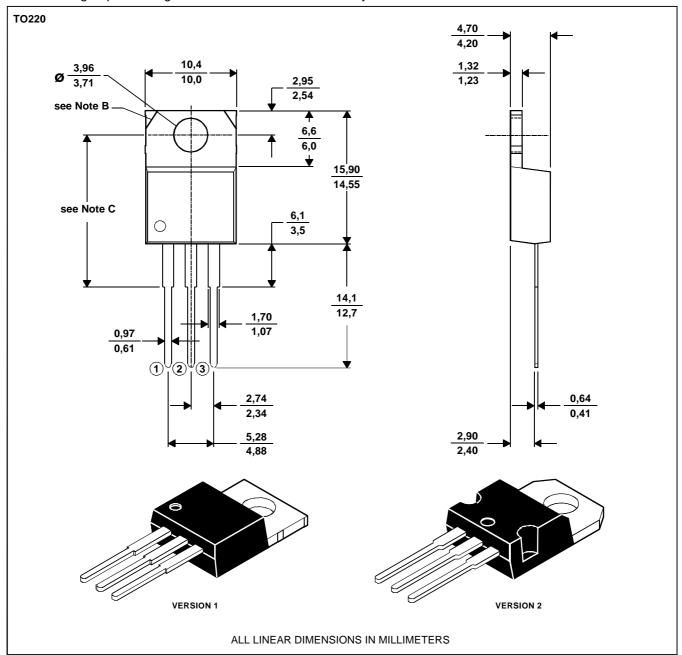
# PRODUCT INFORMATION

### **MECHANICAL DATA**

### **TO-220**

### 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

B. Mounting tab corner profile according to package version.

C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm. MDXXBE



# BD543, BD543A, BD543B, BD543C NPN SILICON POWER TRANSISTORS

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